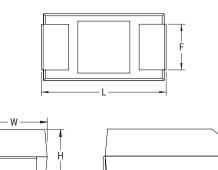


CATHODE (-) END VIEW

T555B107K060AT

T555, Tantalum, Polymer Tantalum, HRA, 100 uF, 10%, 60 VDC, N/A, 100 mOhms, 9.6 mm, 3 mm

## BOTTOM VIEW



►S-

Click here for the 3D model.

**General Information** T555 Series Dielectric Polymer Tantalum Style SMD Chip RoHS No SCIP Number 43449f08-bd3e-4b72-a04c-6c a7dd4144ff Termination Tin AEC-Q200 No Typical Component Weight 5.54 g Shelf Life 156 Weeks

Dimensions		Speci
L	24.5mm +/-0.5mm	Capa
W	8.5mm +/-0.5mm	Tolera
н	9.1mm +/-0.5mm	Volta
S	3mm +/-0.3mm	Town
F	4.2mm +/-0.5mm	Temp
•		Rated
Packaging Specifications		Life

**-** S

SIDE VIEW

Packaging Specifications	
ulk, Box	
0	

Specifications	
Capacitance	100 uF
Tolerance	10%
Voltage DC	60 VDC, 46.8 VDC (105°C), 69 VDC (85°C)
Temperature Range	-55/+105°C
Rated Temperature	85°C
Life	2000 Hrs
Dissipation Factor	5% (120Hz 25C)
Failure Rate	N/A
ESR	100 mOhm (100kHz 25C)
Ripple Current	1660 mAmps (40kHz 85C)
Leakage Current	45 uA (5min 25°C)
Testing and Reliability	25C +/-5C, 10 cycles, after constant voltage conditioning (KEMET standard)

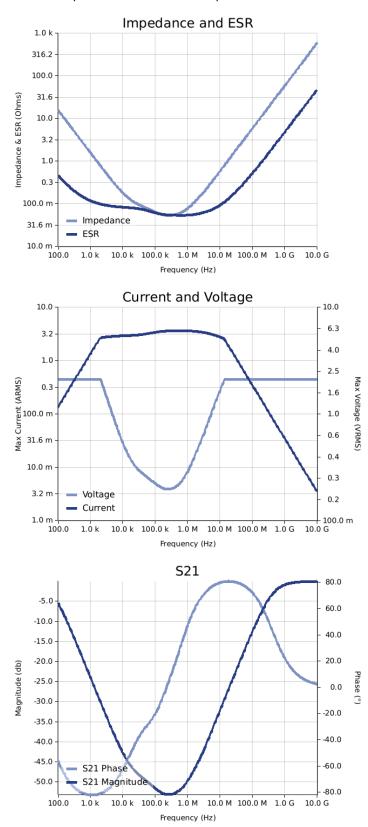
Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute - and we specifically disclaim - any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.

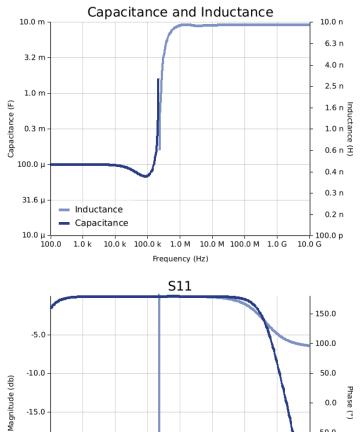


T555B107K060AT T555, Tantalum, Polymer Tantalum, HRA, 100 uF, 10%, 60 VDC, N/A, 100 mOhms, 9.6 mm, 3 mm

## Simulations

For the complete simulation environment please visit K-SIM.





10.0 k 100.0 k 1.0 M 10.0 M 100.0 M 1.0 G

Frequency (Hz)

-15.0

-20.0

-25.0

100.0

S11 Phase

1.0 k

S11 Magnitude

-50.0

-100.0

-150.0

10.0 G



## These are simulations.

This is not a specification!

The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

The responses shown do not represent a specified or implied maximum capability of the device for all applications.

- The ESR used for ripple "Ripple Current/Voltage vs. Frequency" plots is the ESR at ambient temperature.

- The ESR used for http:// Ripple Current/ voltage vs. requertly plots is the ESR at an other temperature.
  The ESR in the "Temperature Rise vs. Ripple Current" plots is adjusted to each incremental temperature rise before the power and ripple current is calculated.
  The effects shown herein are based on measured data from a multiple part sample of the parts in question.
  Ripple capability of this device will be factored by thermal resistance (Rth) created by circuit traces (addi affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.
  The peak voltages generated in the "Temperature Rise vs. Combined Ripple Currents" plot are calculated for each frequency and are not combined with voltages
- generated at any other harmonics.
  Please consult with the catalog or field applications engineer for maximum capability of the device in specific applications.

All product information and data (collectively, the "Information") are subject to change without notice.

KEMET K-SIM is designed to simulate behavior of components with respect to frequency, ambient temperature, and DC bias levels. The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation effects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

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If you have any questions please contact K-SIM.